

SLA6010

Silicon NPN Triple Diffused Planar Darlington
Silicon PNP Epitaxial Planar Darlington

Maximum Ratings

($T_a = 25^\circ\text{C}$)

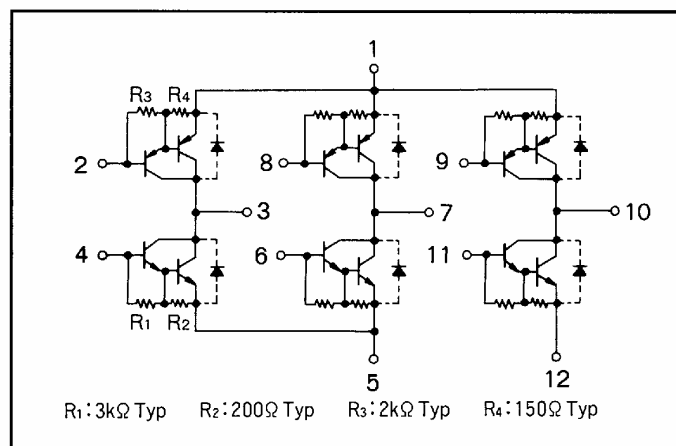
Item	Symbol	NPN	PNP	Unit
Collector-to-Base Voltage	V_{CB0}	60	-60	V
Collector-to-Emitter Voltage	V_{CE0}	60	-60	V
Emitter-to-Base Voltage	V_{EB0}	6	-6	V
Collector Current	I_c	4	-4	A
Collector Current	I_{CP}	6 ($P_w \leq 1\text{ms}$, $D_u \leq 50\%$)		A
Base Current	I_B	0.5	-0.5	A
Total Power Dissipation	P_T	5 ($T_a = 25^\circ\text{C}$)		W
		25 ($T_c = 25^\circ\text{C}$)		
Insulation Breakdown Voltage	V_{ISO}	1000 (Between fin and lead pin, AC)		Vrms
Storage Temperature	T_{stg}	-40 ~ +150		$^\circ\text{C}$
Thermal Resistance	θ_{j-c}	5		$^\circ\text{C}/\text{W}$

Electrical Characteristics

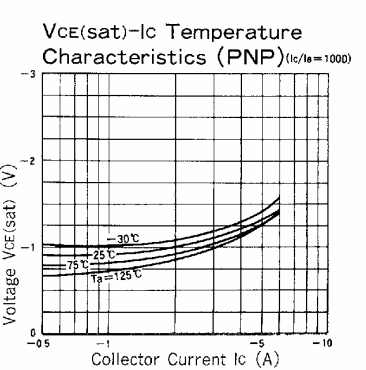
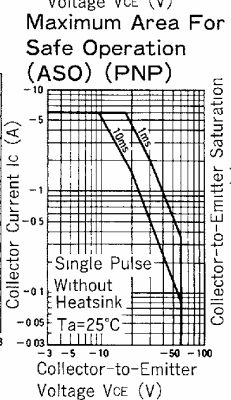
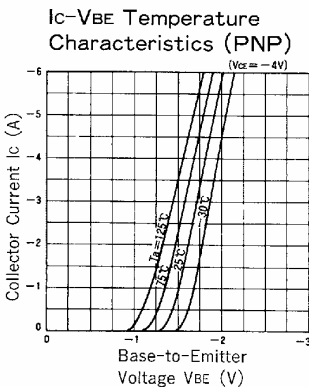
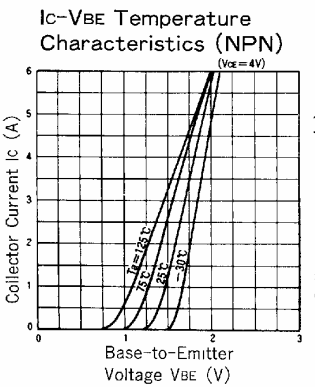
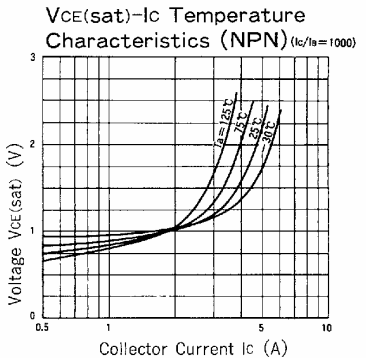
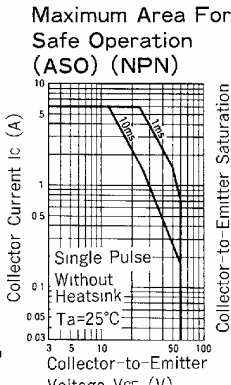
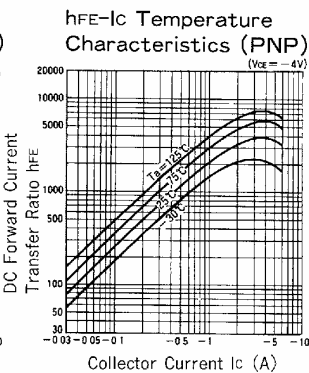
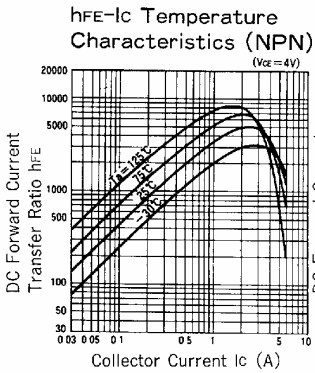
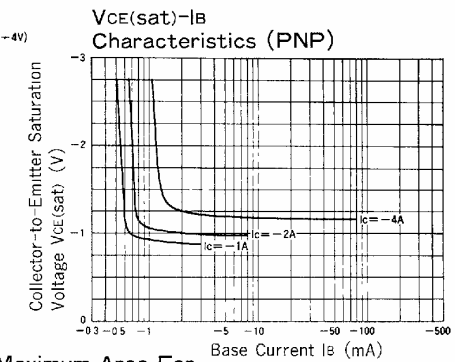
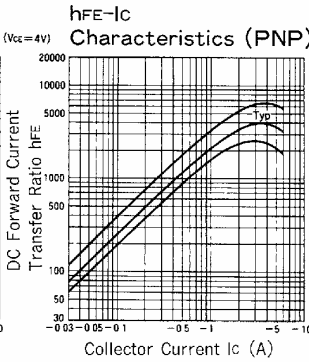
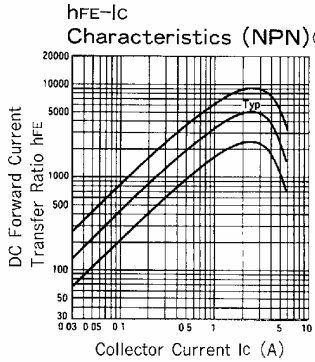
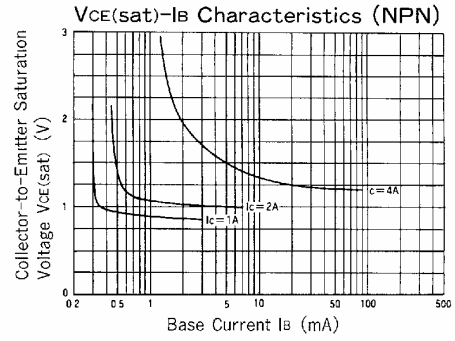
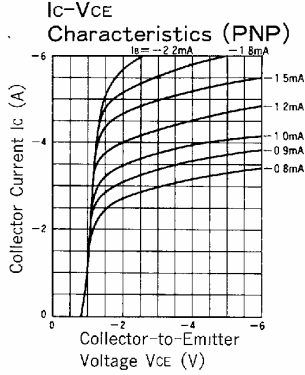
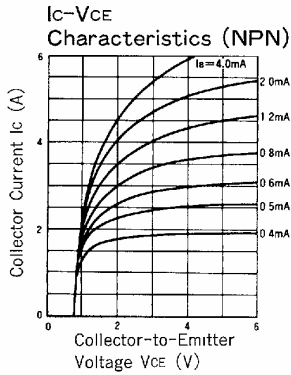
($T_a = 25^\circ\text{C}$)

Item	Symbol	NPN	PNP
Collector Cut-off Current	I_{CBO}	$10\mu\text{Amax}$ ($V_{CB} = 60\text{V}$)	$-10\mu\text{Amax}$ ($V_{CB} = -60\text{V}$)
Emitter Cut-off Current	I_{EBO}	10mAmax ($V_{EB} = 6\text{V}$)	-10mAmax ($V_{EB} = -6\text{V}$)
Collector-to-Emitter Voltage	V_{CE0}	60Vmin ($I_c = 10\text{mA}$)	-60Vmin ($I_c = -10\text{mA}$)
DC Forward Current Transfer Ratio	h_{FE}	2000min ($V_{CE} = 4\text{V}$, $I_c = 3\text{A}$)	2000min ($V_{CE} = -4\text{V}$, $I_c = -3\text{A}$)
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	1.5Vmax ($I_c = 3\text{A}$, $I_B = 6\text{mA}$)	-1.5Vmax ($I_c = -3\text{A}$, $I_B = -6\text{mA}$)

Equivalent Circuit Diagram



Characteristic Curves

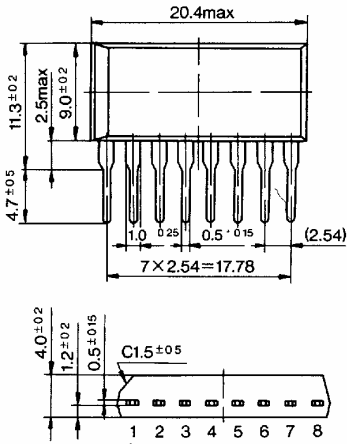


Notes on using products

Outline Drawings (Unit:in mm)

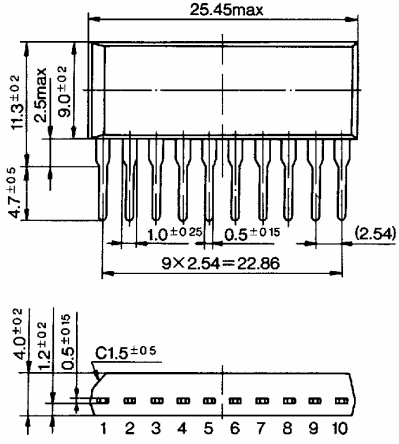
STA Family

STA300 Series



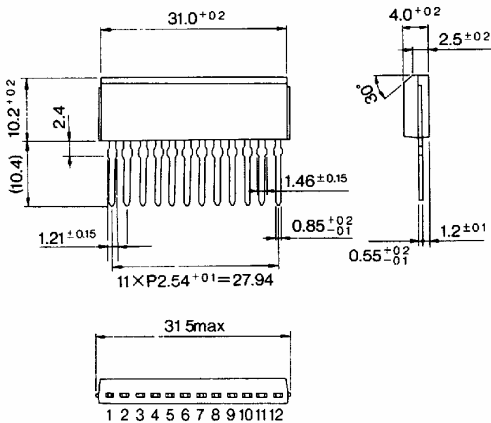
Weight Approx. 2.0g

STA400 Series



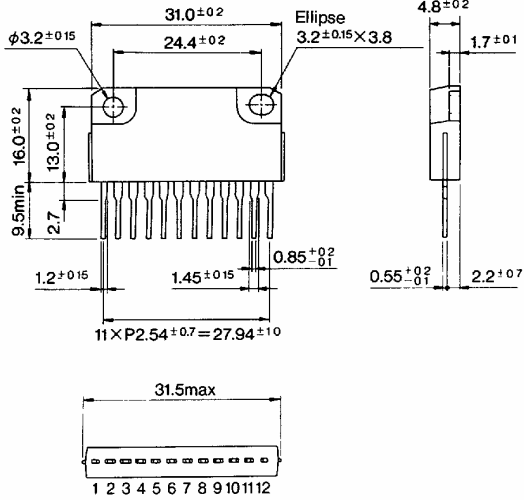
Weight Approx. 2.6g

SMA Family



Weight Approx. 4.0g

SLA Family



Weight Approx. 6.0g